

EPC2014C

EPC2014C Information



Part Number	EPC2014C
Manufacturer	EPC
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Description	TRANS GAN 40V 10A BUMPED DIE
Package	Die
	For the pricing/inventory/lead time, please contact us
	Website: https://www.heisener.com
	E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



EPC2014C Specifications

Manufacturer Part Number	EPC2014C
Manufacturer	EPC
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	Die
Series	eGaN?
FET Type	N-Channel
Technology	GaNFET (Gallium Nitride)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	5V
Vgs(th) (Max) @ Id	2.5V @ 2mA
Gate Charge (Qg) (Max) @ Vgs	2.5nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	300pF @ 20V
Vgs (Max)	+6V, -4V
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	16 mOhm @ 10A, 5V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	Die Outline (5-Solder Bar)
Package / Case	Die
	Report errors?

EPC2014C Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE SUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

EPC2014C Payment Methods



EPC2014C Shipping Methods



If you have any question about EPC2014C, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com